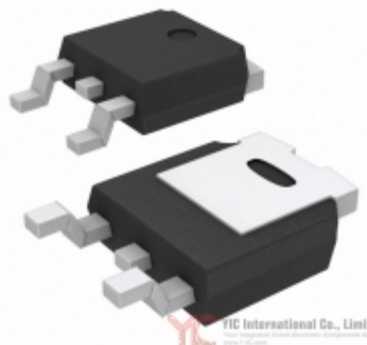

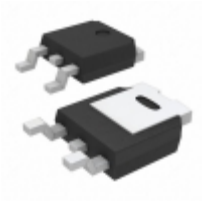
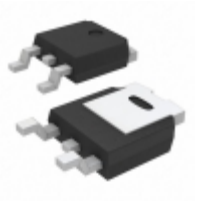
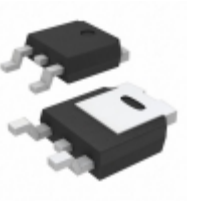
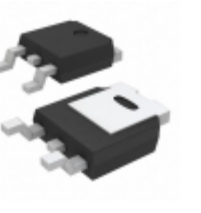

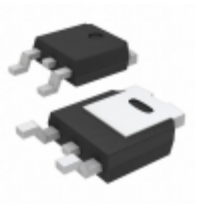
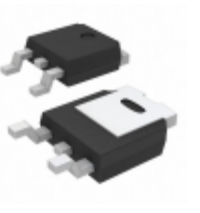
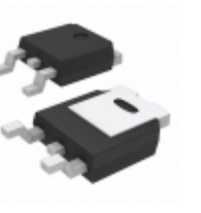
	<h2>STD7N65M2</h2>	
	Hersteller-Teilenummer:	STD7N65M2
	Hersteller / Marke:	STMicroelectronics
	Teil der Beschreibung:	MOSFET N-CH 650V 5A DPAK
Datenblätter:	 STD7N65M2.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 787 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	STD7N65M2
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 650V 5A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	787 pcs Stock
Serie	MDmesh™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	60W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	650V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	5A (Tc)
Rds On (Max) @ Id, Vgs	1.15 Ohm @ 2.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	270pF @ 100V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Original-Reel®

STD7N65M2 ist neu im Original, Suche STD7N65M2 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD7N65M2 STMicroelectronics mit Garantie und Vertrauen.
Anfrage STD7N65M2: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>STD7N80K5 STMicroelectronics MOSFET N-CH 800V 6A DPAK</p>	 <p>STD7N90K5 STMicroelectronics N-CHANNEL 800 V, 0.75 OHM TYP.,</p>	 <p>STD7LN80K5 STMicroelectronics MOSFET N-CH 800V 5A DPAK</p>	 <p>STD7NK30Z STMicroelectronics MOSFET N-CH 300V 5A DPAK</p>
 <p>STD7N52K3 STMicroelectronics MOSFET N-CH 525V 6.2A DPAK</p>	 <p>STD7ANM60N STMicroelectronics MOSFET N-CH 600V DPAK</p>	 <p>STD7N52DK3 STMicroelectronics MOSFET N-CH 525V 6A DPAK</p>	 <p>STD7N60M2 STMicroelectronics MOSFET N-CH 600V DPAK</p>

heiße Teile

Mehr

⊕ STD70GK08B	↔ STD70GK12	⇒ STD70GK12B	D STD70GK14	⇒ STD70GK14B
⊖ STD70GK16	⊕ STD70GK16B	D STD70GK18	⇒ STD70GK18B	⇒ STD70N02
⊕ STD70N02L	⊖ STD70N02L-1	⊕ STD70N02LH5	↔ STD70N03L	⇒ STD70N03LT4
D STD70N10F4	⊕ STD70N2LH5	⊖ STD70N6F3	⊕ STD70NH02L	⇒ STD70NH02LT4
⇒ STD70NS04ZL	↔ STD75N3LLH6	⊕ STD7N52DK3	⊖ STD7N52K3	⇒ STD7N60M2
↔ STD7NB20	⇒ STD7NB20T4	D STD7NK30Z	⊕ STD7NK40Z	⊖ STD7NK40Z-1
⊕ STD7NK40ZT4	D STD7NM50N	⇒ STD7NM60	↔ STD7NM60N	⇒ STD7NM60N-1
⊖ STD7NM64D	⊕ STD7NM64N	↔ STD7NM80	⇒ STD7NM80-1	⇒ STD7NS20-1
⊕ STD7NS20T4	⊖ STD80N02	⊕ STD80N02-011G	D STD80N10F7	⇒ STD80N4F6
↔ STD80N6F6	⊕ STD80N6F7	⊖ STD815CP40	⊕ STD83003	⇒ STD83003-1

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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